## ULQ2003A-Q1, ULQ2004A-Q1, HIGH-VOLTAGE HIGH-CURRENT DARLINGTON TRANSISTOR ARRAY

1B

2B 🛮 2

5B

6B

7B

Е

3B 🛚 3

4B 🛮 4

5

7

8

**D PACKAGE** 

(TOP VIEW)

16 1 1C

15 2C

14∏ 3C

13 4C

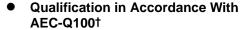
12**∏** 5C

11 6C

10**∏** 7C

9П СОМ

SGLS148 - DECEMBER 2002



- Qualified for Automotive Applications
- Customer-Specific Configuration Control Can Be Supported Along With Major-Change Approval
- ESD Protection Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)
- 500-mA Rated Collector Current (Single Output)
- High-Voltage Outputs . . . 50 V
- Output Clamp Diodes
- Inputs Compatible With Various Types of Logic
- Relay-Driver Applications

### description

The ULQ2003A-Q1 and ULQ2004A-Q1 are high-voltage, high-current Darlington transistor arrays. Each consists of seven npn Darlington pairs that feature high-voltage outputs with common-cathode clamp diodes for switching inductive loads. The collector-current rating of a single Darlington pair is 500 mA. The Darlington pairs can be paralleled for higher current capability. Applications include relay drivers, hammer drivers, lamp drivers, display drivers (LED and gas discharge), line drivers, and logic buffers.

The ULQ2003A-Q1 has a 2.7-k $\Omega$  series base resistor for each Darlington pair, for operation directly with TTL or 5-V CMOS devices. The ULQ2004A-Q1 has a 10.5-k $\Omega$  series base resistor to allow operation directly from CMOS devices that use supply voltages of 6 V to 15 V. The required input current of the ULQ2004A-Q1 is below that of the ULQ2003A-Q1.

### **AVAILABLE OPTIONS**

_	D PACKAGES <sup>†</sup>		
T <sub>A</sub>	SMALL OUTLINE		
–40°C to 105°C	ULQ2003ATDQ1 ULQ2003ATDRQ1		
	ULQ2004ATDQ1 <sup>‡</sup> ULQ2004ATDRQ1 <sup>‡</sup>		

<sup>&</sup>lt;sup>†</sup>The D package is available taped and reeled. Add the suffix R to device type (e.g., ULQ2003TDADRQ1).



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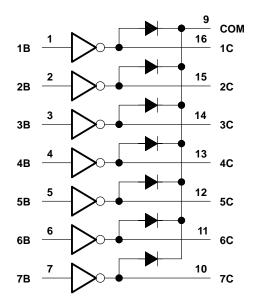
<sup>†</sup> Contact factory for details. Q100 qualification data available on request.

<sup>‡</sup>ULQ2004ATDQ1 and ULQ2004ATDRQ1 are Product Preview only.

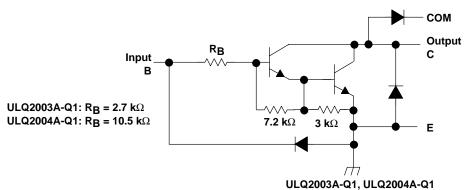
# ULQ2003A-Q1, ULQ2004A-Q1, HIGH-VOLTAGE HIGH-CURRENT DARLINGTON

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### logic diagram



### schematics (each Darlington pair)



All resistor values shown are nominal.

# absolute maximum ratings at 25°C free-air temperature (unless otherwise noted)†

Collector-emitter voltage	50 V
Clamp diode reverse voltage (see Note 1)	
Input voltage, V <sub>I</sub> (see Note 1)	
Peak collector current (see Figure 14)	500 mA
Output clamp current, I <sub>OK</sub>	500 mA
Total emitter-terminal current	–2.5 A
Continuous total power dissipation	See Dissipation Rating Table
Package thermal impedance, θ <sub>JA</sub> (see Note 2)	73°C/W
Operating free-air temperature range, T <sub>A</sub> ,	–40°C to 105°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C
Storage temperature range, T <sub>stg</sub>	

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. All voltage values are with respect to the emitter/substrate terminal E, unless otherwise noted.
  - 2. The package thermal impedance is calculated in accordance with JESD 51-7.



### **DISSIPATION RATING TABLE**

PACKAGE	T <sub>A</sub> = 25°C	DERATING FACTOR	T <sub>A</sub> = 85°C	T <sub>A</sub> = 105°C
	POWER RATING	ABOVE T <sub>A</sub> = 25°C	POWER RATING	POWER RATING
D	950 mW	7.6 mW/°C	494 mW	342 mW

## electrical characteristics over recommended operating conditions (unless otherwise noted)

PARAMETER		TEST CONDITIONS		ULQ2003A-Q1		ULQ2004A-Q1				
				MIN	TYP	MAX	MIN	TYP	MAX	UNIT
	On-state input voltage, See Figure 6		$I_C = 125 \text{ mA}$						5	V
			$I_C = 200 \text{ mA}$			2.7			6	
			$I_C = 250 \text{ mA}$			2.9				
V <sub>I(on)</sub>		V <sub>CE</sub> = 2 V	$I_C = 275 \text{ mA}$						7	
			$I_C = 300 \text{ mA}$			3				
			$I_C = 350 \text{ mA}$						8	
	Collector-emitter saturation voltage, See Figure 5	$I_I = 250 \mu A$ ,	$I_C = 100 \text{ mA}$		0.9	1.2		0.9	1.1	V
VCE(sat)		$I_{I} = 350  \mu A$ ,	$I_C = 200 \text{ mA}$		1	1.4		1	1.3	
` '		$I_{I} = 500 \mu A$ ,	$I_C = 350 \text{ mA}$		1.2	1.7		1.2	1.6	
	Collector cutoff current	V <sub>CE</sub> = 50 V, See Figure 1	$I_{\parallel} = 0$ ,			100			50	
ICEX		V <sub>CE</sub> = 50 V, See Figure 2	I <sub>I</sub> = 0						100	μΑ
			V <sub>I</sub> = 1 V						500	
٧F	Clamp forward voltage, See Figure 8	I <sub>F</sub> = 350 mA			1.7	2.2		1.7	2	V
I <sub>I(off)</sub>	Off-state input current, See Figure 3	V <sub>CE</sub> = 50 V,	I <sub>C</sub> = 500 μA	30	65		50	65		μΑ
	Input current, see Figure 4	V <sub>I</sub> = 3.85 V			0.93	1.35				
Ц		V <sub>I</sub> = 5 V						0.35	0.5	mA
		V <sub>I</sub> = 12 V						1	1.45	
I <sub>R</sub>	Clamp reverse current, See Figure 7	$V_R = 50 V$ ,	T <sub>A</sub> = 25°C			100			50	μΑ
		V <sub>R</sub> = 50 V				100			100	
Ci	Input capacitance	$V_I = 0$ ,	f = 1 MHz		15	25		15	25	pF

# switching characteristics over recommended operating conditions (unless otherwise noted)

PARAMETER		TEST CONDITIONS	ULQ2003A-Q1, ULQ2004A-Q1			UNIT
			MIN	TYP	MAX	<u> </u>
tPLH	Propagation delay time, low-to-high level output	See Figure 9		1	10	μs
tPHL	Propagation delay time, high-to-low level output	See Figure 9		1	10	μs
Vон	High-level output voltage after switching	$V_S = 50 \text{ V}, \qquad I_O \approx 300 \text{ mA},$ See Figure 10	V <sub>S</sub> -500		·	mV



### PARAMETER MEASUREMENT INFORMATION

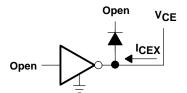


Figure 1. I<sub>CEX</sub> Test Circuit

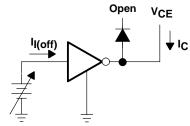
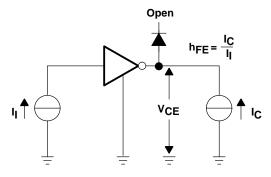


Figure 3. I<sub>I(off)</sub> Test Circuit



NOTE: I<sub>I</sub> is fixed for measuring  $V_{CE(sat)}$ , variable for measuring h<sub>FE</sub>.

Figure 5. hFE, VCE(sat) Test Circuit

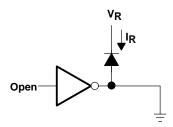


Figure 7. I<sub>R</sub> Test Circuit

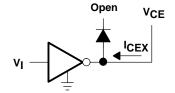


Figure 2. I<sub>CEX</sub> Test Circuit

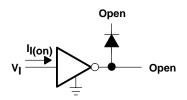


Figure 4. I<sub>I</sub> Test Circuit

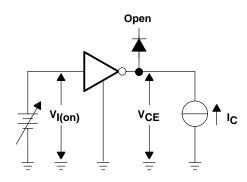


Figure 6. V<sub>I(on)</sub> Test Circuit

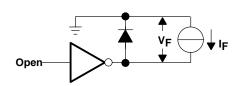


Figure 8. V<sub>F</sub> Test Circuit

### PARAMETER MEASUREMENT INFORMATION

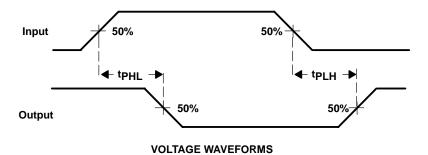
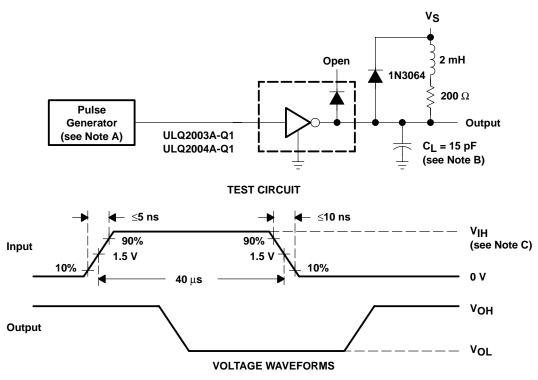


Figure 9. Propagation Delay-Time Waveforms



NOTES: A. The pulse generator has the following characteristics: PRR = 12.5 kHz,  $Z_O$  = 50  $\Omega$ .

- B. C<sub>L</sub> includes probe and jig capacitance.
- C. For testing the ULQ2003A-Q1,  $V_{IH} = 3 \text{ V}$ ; for the ULQ2004A-Q1,  $V_{IH} = 8 \text{ V}$ .

Figure 10. Latch-Up Test Circuit and Voltage Waveforms

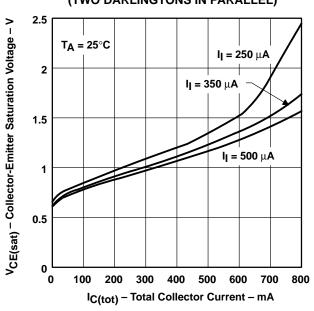
### **TYPICAL CHARACTERISTICS**

### **COLLECTOR-EMITTER SATURATION VOLTAGE**

**COLLECTOR CURRENT** (ONE DARLINGTON) VCE(sat) - Collector-Emitter Saturation Voltage - V 2.5 T<sub>A</sub> = 25°C 2  $I_{I} = 250 \mu A$  $I_1 = 350 \mu A$  $I_I = 500 \mu A$ 1.5 1 0.5 700 800 0 100 200 300 400 500 600 IC - Collector Current - mA

Figure 11

# COLLECTOR-EMITTER SATURATION VOLTAGE vs TOTAL COLLECTOR CURRENT (TWO DARLINGTONS IN PARALLEL)



### Figure 12

### **COLLECTOR CURRENT**

**INPUT CURRENT** 500  $R_L = 10 \Omega$ 450  $T_A = 25^{\circ}C$ I<sub>C</sub> - Collector Current - mA 400 V<sub>S</sub> = 10 V 350 V<sub>S</sub> = 8 V 300 250 200 150 100 50 0 0 25 50 75 100 125 150 175 200 I<sub>I</sub> - Input Current - μA

Figure 13



### THERMAL INFORMATION

## MAXIMUM COLLECTOR CURRENT

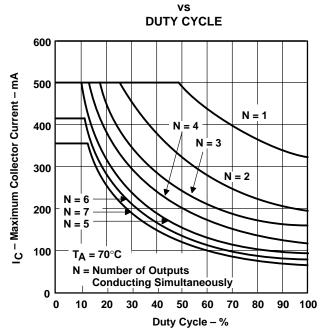


Figure 14

### **APPLICATION INFORMATION**

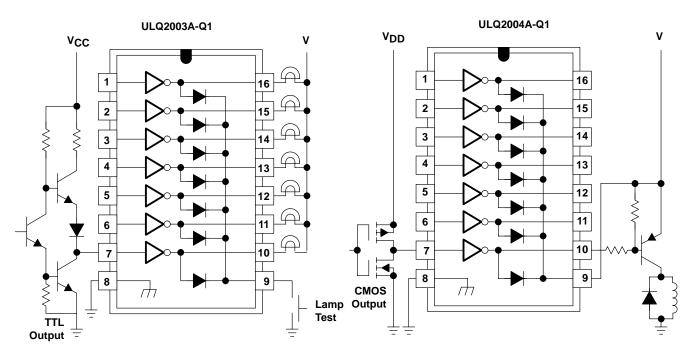


Figure 15. TTL to Load

Figure 16. Buffer for Higher Current Loads

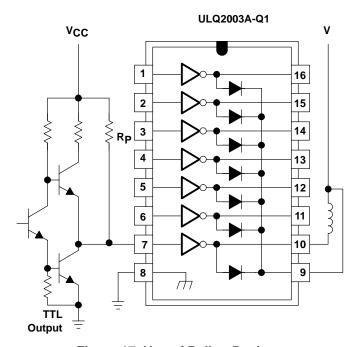


Figure 17. Use of Pullup Resistors to Increase Drive Current

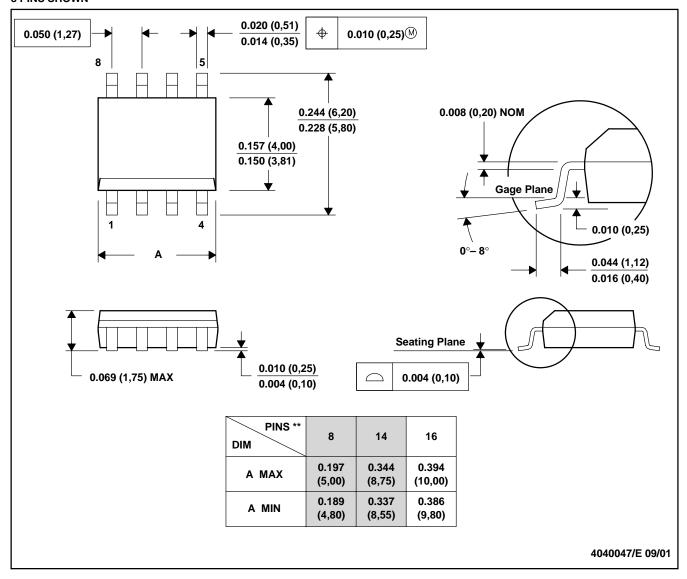


### **MECHANICAL DATA**

### D (R-PDSO-G\*\*)

### 8 PINS SHOWN

### PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

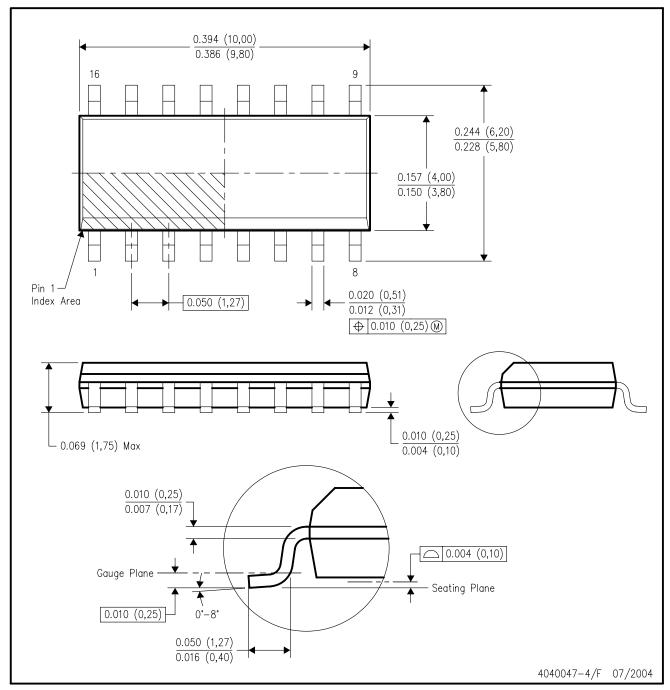
B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0.006 (0,15).

D. Falls within JEDEC MS-012

# D (R-PDSO-G16)

# PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-012 variation AC.



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